

isc N-Channel MOSFET Transistor

STW5NK100Z

FEATURES

- Drain Current : ID= 3.5A@ TC=25 $^{\circ}\mathrm{C}$
- Drain Source Voltage
 - : V_{DSS}= 1000V(Min)
- Static Drain-Source On-Resistance
 - : $R_{DS(on)} = 3.7 \Omega (Max)$
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

DESCRIPTION

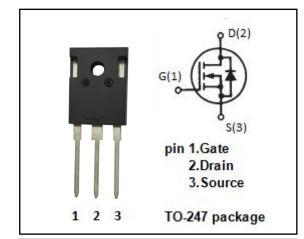
 motor drive, DC-DC converter, power switch and solenoid drive.

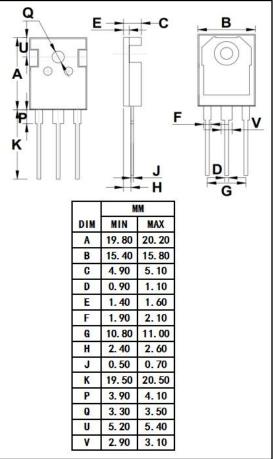
ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

SYMBOL	PARAMETER	VALUE	UNIT
V _{DSS}	Drain-Source Voltage 1000		V
V _{GS}	Gate-Source Voltage-Continuous ±30		V
I _D	Drain Current-Continuous	3.5	Α
I _{DM}	Drain Current-Single Pluse	14	А
P _D	Total Dissipation @Tc=25℃	125	W
TJ	Max. Operating Junction Temperature -55~150		$^{\circ}$
T _{stg}	Storage Temperature -55~150		$^{\circ}$

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
R _{th j-c}	Thermal Resistance, Junction to Case	1.0	°C/W





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ELECTRICAL CHARACTERISTICS

T_C=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	MAX	UNIT
V _{(BR)DSS}	Drain-Source Breakdown Voltage	V _{GS} = 0; I _D = 1mA	1000		V
V _{GS(th)}	Gate Threshold Voltage	V _{DS} = 10V; I _D = 1mA	3.0	4.5	V
R _{DS(on)}	Drain-Source On-Resistance	V _{GS} = 10V; I _D = 1.75A		3.7	Ω
I _{GSS}	Gate-Body Leakage Current	V _{GS} = ±20V;V _{DS} = 0		±10	uA
I _{DSS}	Zero Gate Voltage Drain Current	V _{DS} = 1000V; V _{GS} = 0		1.0	uA
V _{SD}	Forward On-Voltage	I _S = 3.5A; V _{GS} = 0	-	1.6	V

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